- Inputs Are TTL-Voltage Compatible
- EPIC™ (Enhanced-Performance Implanted CMOS) 1-μm Process
- Package Options Include Plastic Small-Outline (D), Shrink Small-Outline (DB), Thin Shrink Small-Outline (PW), DIP (N) Packages, Ceramic Chip Carriers (FK), Flat (W), and DIP (J) Packages

#### description

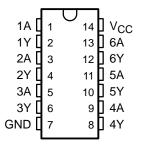
The 'ACT04 contain six independent inverters. The devices perform the Boolean function  $Y = \overline{A}$ .

The SN54ACT04 is characterized for operation over the full military temperature range of -55°C to 125°C. The SN74ACT04 is characterized for operation from -40°C to 85°C.

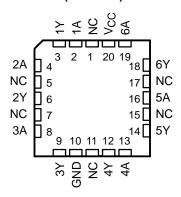
FUNCTION TABLE (each inverter)

INPUT A	OUTPUT Y
Н	L
L	Н

#### SN54ACT04 . . . J OR W PACKAGE SN74ACT04 . . . D, DB, N, OR PW PACKAGE (TOP VIEW)

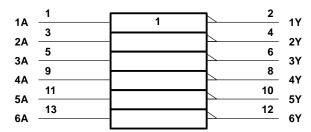


#### SN54ACT04 . . . FK PACKAGE (TOP VIEW)



NC - No internal connection

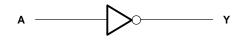
# logic symbol†



<sup>†</sup> This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

Pin numbers shown are for the D, DB, J, N, PW, and W packages.

# logic diagram, each inverter (positive logic)





Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

EPIC is a trademark of Texas Instruments Incorporated



SCAS518A - JULY 1995 - REVISED APRIL 1996

# absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V <sub>CC</sub>		0.5 V to 7 V
Input voltage range, V <sub>I</sub> (see Note 1)		$-0.5 \text{ V to V}_{CC} + 0.5 \text{ V}$
Output voltage range, VO (see Note 1)		$-0.5 \text{ V to V}_{CC} + 0.5 \text{ V}$
Input clamp current, $I_{ K }(V_1 < 0 \text{ or } V_1 > V_{CC})$		±20 mA
Output clamp current, I <sub>OK</sub> (V <sub>O</sub> < 0 or V <sub>O</sub> > V <sub>CC</sub> )		±20 mA
Continuous output current, $I_O$ ( $V_O = 0$ to $V_{CC}$ )		±50 mA
Continuous current through V <sub>CC</sub> or GND		±200 mA
Maximum power dissipation at $T_A = 55^{\circ}C$ (in still air) (see Note 2):	D package	1.25 W
	DB package	0.5 W
	N package	1.1 W
	PW package	0.5 W
Storage temperature range, T <sub>Stg</sub>		65°C to 150°C

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

# recommended operating conditions (see Note 3)

		SN54ACT04		SN74A	UNIT	
		MIN	MIN MAX		MIN MAX	
Vсс	Supply voltage	4.5	5.5	4.5	5.5	V
$V_{IH}$	High-level input voltage	2		2		V
$V_{IL}$	Low-level input voltage		0.8		0.8	V
٧ <sub>I</sub>	Input voltage	0	VCC	0	VCC	V
٧o	Output voltage	0	VCC	0	VCC	V
ЮН	High-level output current		- 24		- 24	mA
loL	Low-level output current		24		24	mA
$\Delta t/\Delta v$	Input transition rise or fall rate	0	8	0	8	ns/V
T <sub>A</sub>	Operating free-air temperature	-55	125	-40	85	°C

NOTE 3: Unused inputs must be held high or low to prevent them from floating.



<sup>2.</sup> The maximum package power dissipation is calculated using a junction temperature of 150°C and a board trace length of 750 mils, except for the N package, which has a trace length of zero.

# electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

DADAMETED	TEST CONDITIONS	T ,,	Т	A = 25°C	;	SN54A	CT04	SN74A	CT04	LINUT
PARAMETER		vcc	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
	10.1 FO.11A	4.5 V	4.4	4.49		4.4		4.4		
	I <sub>OH</sub> = -50 μA	5.5 V	5.4	5.49		5.4		5.4		
Vari		4.5 V	3.86			3.7		3.76		٧
VOH	$I_{OL} = -24 \text{ mA}$	5.5 V	4.86			4.7		4.76		
	$I_{OH} = -50 \text{ mA}^{\dagger}$	5.5 V				3.85				
	$I_{OH} = -75 \text{ mA}^{\dagger}$	5.5 V						3.85		
	$I_{OL} = 50 \mu A$ $I_{OL} = 24 \text{ mA}$	4.5 V		0.001	0.1		0.1		0.1	٧
		5.5 V		0.001	0.1		0.1		0.1	
\/a		4.5 V			0.36		0.5		0.44	
VOL		5.5 V			0.36		0.5		0.44	
	I <sub>OL</sub> = 50 mA <sup>†</sup>	5.5 V					1.65			
	I <sub>OL</sub> = 75 mA <sup>†</sup>	5.5 V							1.65	
ΙĮ	V <sub>I</sub> = V <sub>CC</sub> or GND	5.5 V			±0.1		±1		±1	μΑ
Icc	$V_I = V_{CC}$ or GND, $I_O = 0$	5.5 V			2		40		20	μΑ
∆l <sub>CC</sub> ‡	One input at 3.4 V, Other inputs at GND or V <sub>CC</sub>	5.5 V		0.6			1.6		1.5	mA
C <sub>i</sub>	$V_I = V_{CC}$ or GND	5 V		4.5					·	pF

<sup>†</sup> Not more than one output should be tested at a time, and the duration of the test should not exceed 2 ms.

# switching characteristics over recommended operating free-air temperature range, $V_{CC}$ = 5 V $\pm$ 0.5 V (unless otherwise noted) (see Figure 1)

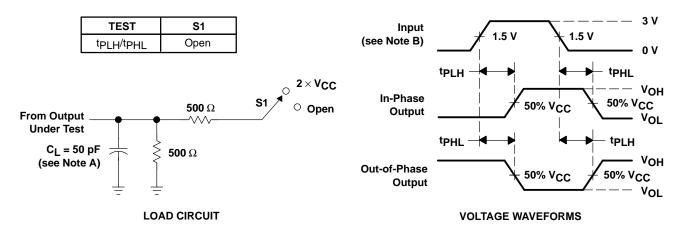
PARAMETER	FROM	то	T,	4 = 25°C	;	SN54A	CT04	SN74A	CT04	UNIT
	(INPUT)	(OUTPUT)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
t <sub>PLH</sub>	А	V	1	6	8.5	1	9	1	9	ns
t <sub>PHL</sub>		ľ	1	5.5	8	1	8.5	1	8.5	115

# operating characteristics, $V_{CC} = 5 \text{ V}$ , $T_A = 25^{\circ}\text{C}$

PARAMETER		TEST CON	TYP	UNIT	
C <sub>pd</sub>	Power dissipation capacitance	$C_L = 50 \text{ pF},$	f = 1 MHz	45	pF

<sup>&</sup>lt;sup>‡</sup> This is the increase in supply current for each input that is at one of the specified TTL voltage levels rather than 0 V or V<sub>CC</sub>.

#### PARAMETER MEASUREMENT INFORMATION



NOTES: A. C<sub>L</sub> includes probe and jig capacitance.

- B. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  1 MHz,  $Z_Q = 50 \ \Omega$ ,  $t_f \leq 2.5 \ ns$ ,  $t_f \leq 2.5 \ ns$ .
- C. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms

#### **IMPORTANT NOTICE**

Texas Instruments (TI) reserves the right to make changes to its products or to discontinue any semiconductor product or service without notice, and advises its customers to obtain the latest version of relevant information to verify, before placing orders, that the information being relied on is current.

TI warrants performance of its semiconductor products and related software to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are utilized to the extent TI deems necessary to support this warranty. Specific testing of all parameters of each device is not necessarily performed, except those mandated by government requirements.

Certain applications using semiconductor products may involve potential risks of death, personal injury, or severe property or environmental damage ("Critical Applications").

TI SEMICONDUCTOR PRODUCTS ARE NOT DESIGNED, INTENDED, AUTHORIZED, OR WARRANTED TO BE SUITABLE FOR USE IN LIFE-SUPPORT APPLICATIONS, DEVICES OR SYSTEMS OR OTHER CRITICAL APPLICATIONS.

Inclusion of TI products in such applications is understood to be fully at the risk of the customer. Use of TI products in such applications requires the written approval of an appropriate TI officer. Questions concerning potential risk applications should be directed to TI through a local SC sales office.

In order to minimize risks associated with the customer's applications, adequate design and operating safeguards should be provided by the customer to minimize inherent or procedural hazards.

TI assumes no liability for applications assistance, customer product design, software performance, or infringement of patents or services described herein. Nor does TI warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right of TI covering or relating to any combination, machine, or process in which such semiconductor products or services might be or are used.

Copyright © 1996, Texas Instruments Incorporated